TOSHIBA

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π -MOSVII)

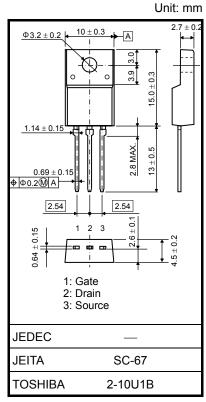
TK9A60D

Switching Regulator Applications

- Low drain-source ON-resistance: $RDS(ON) = 0.67 \Omega(typ.)$
- High forward transfer admittance: $|Y_{fs}| = 4.0 \text{ S}$ (typ.)
- Low leakage current: $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 600 \ V)$
- Enhancement mode: V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_D = 1 mA)

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Characteristics		Symbol	Rating	Unit				
Drain-source voltage		V _{DSS}	600	V				
Gate-source voltage		V _{GSS}	±30	V				
Drain current	DC (Note 1) I _D	9	А				
	Pulse (Note 1) I _{DP}	36	~				
Drain power dissipati	on (Tc = 25° C)	PD	45	W				
Single pulse avalanche energy (Note 2)		E _{AS}	260	mJ				
Avalanche current		I _{AR}	9	А				
Repetitive avalanche	energy (Note 3	E _{AR}	4.5	mJ				
Channel temperature		T _{ch}	150	°C				
Storage temperature range		T _{stg}	-55 to 150	°C				

Absolute Maximum Ratings (Ta = 25°C)



Weight: 1.7 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

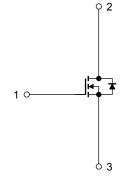
Characteristics	Symbol	Max	Unit	
Thermal resistance, channel to case	R _{th (ch-c)}	2.78	°C/W	
Thermal resistance, channel to ambient	R _{th (ch-a)}	62.5	°C/W	

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: $V_{DD} = 90 \text{ V}, \text{ T}_{ch} = 25^{\circ}C(\text{initial}), \text{ L} = 5.6 \text{ mH}, \text{ R}_{G} = 25 \Omega, \text{ I}_{AR} = 9 \text{ A}$

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Handle with care.



Start of commercial production 2009-05

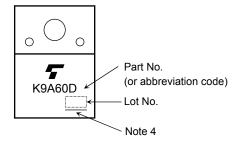
Electrical Characteristics (Ta = 25°C)

Char	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS}=\pm 30~V,~V_{DS}=0~V$	_		±1	μA
Drain cut-off current		I _{DSS}	$V_{DS} = 600 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			10	μA
Drain-source bre	akdown voltage	V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	600		_	V
Gate threshold v	oltage	V _{th}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	2.0		4.0	V
Drain-source ON	resistance	R _{DS (ON)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 4.5 \text{ A}$		0.67	0.83	Ω
Forward transfer	admittance	Y _{fs}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 4.5 \text{ A}$	1.0	4.0	_	S
Input capacitance		C _{iss}		_	1200		
Reverse transfer capacitance		C _{rss}	$V_{DS} = 25 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ f} = 1 \text{ MHz}$		6	_	pF
Output capacitance		Coss		_	120		
Switching time	Rise time	tr	V_{GS} $0 V$ $J_{D} = 4.5 A$ V_{OUT} C $K_{L} = 44 \Omega$ $V_{DD} \approx 200 V$		25	_	- ns
	Turn-on time	t _{on}		_	60	_	
	Fall time	t _f		_	12	_	
	Turn-off time	t _{off}	Duty \leq 1%, t _W = 10 µs	_	100	—	
Total gate charge		Qg		_	24		
Gate-source charge		Q _{gs}	$V_{DD}\approx 400~V,~V_{GS}=10~V,~I_{D}=9~A$	_	16		nC
Gate-drain charge		Q _{gd}		_	8		

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	—	_	_	9	А
Pulse drain reverse current (Note 1)	I _{DRP}	—	_	_	36	А
Forward voltage (diode)	V _{DSF}	$I_{DR} = 9 \text{ A}, V_{GS} = 0 \text{ V}$	_	_	-1.7	V
Reverse recovery time	t _{rr}	$I_{DR} = 9 \text{ A}, V_{GS} = 0 \text{ V},$	_	1300	_	ns
Reverse recovery charge	Q _{rr}	dl _{DR} /dt = 100 A/μs	_	12	_	μC

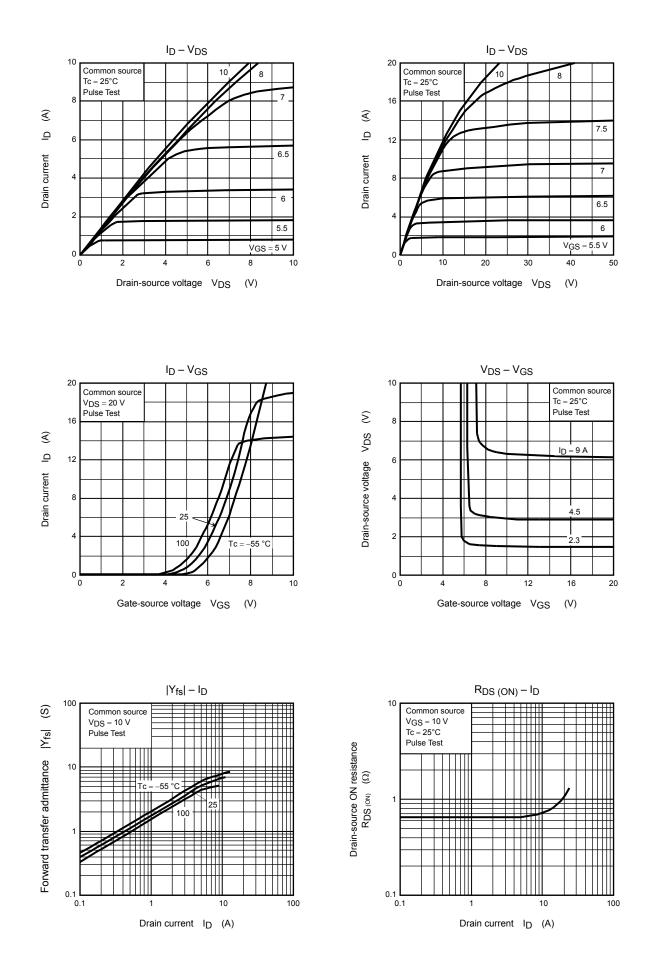
Marking



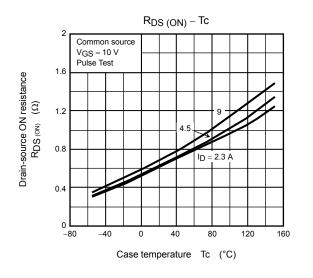
Note 4 : A line under a Lot No. identifies the indication of product Labels [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

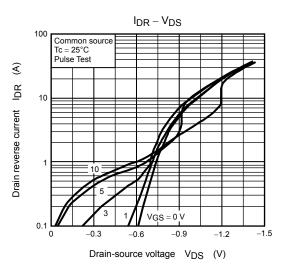
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

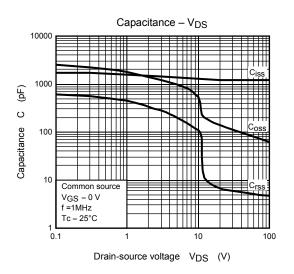
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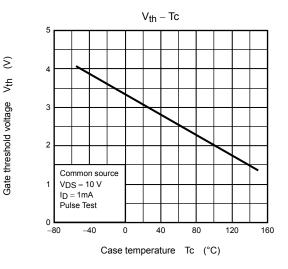


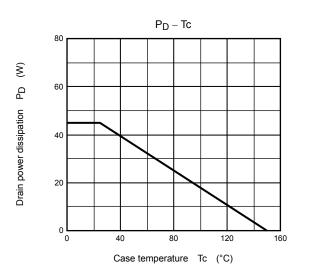
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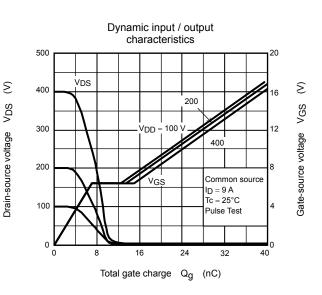


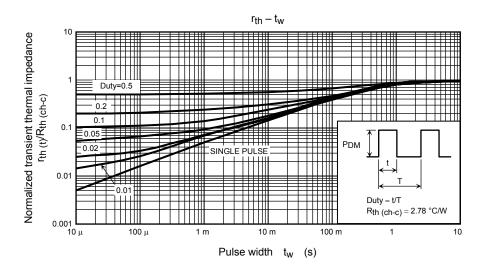


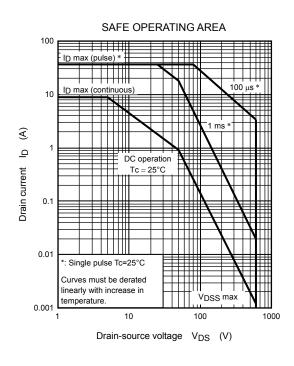


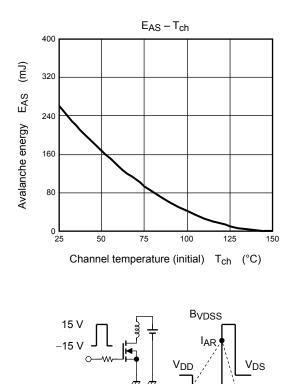












$$R_{G} = 25 \Omega$$

$$V_{DD} = 90 V, L = 5.6 \text{ mH}$$

$$E_{AS} = \frac{1}{2} \cdot L \cdot l^{2} \cdot \left(\frac{B_{VDSS}}{B_{VDSS} - V_{DD}}\right)$$

Test circuit

Waveform

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